## NSN 5961-00-080-3725

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-080-3725 **Inclosure Material:** Metal **Overall Length:** 0.415 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.650 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 breakover voltage, dc **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 20.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 105.0 degrees celsius ambient air **Special Features:** Internal junction configuration arrangement pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0